Technical Data
Data Sheet N2306, Rev. -

Automotive Qualified

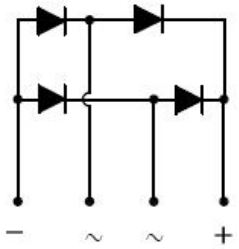
KBJ410G-A
GLASS PASSIVATED SINGLE-PHASE BRIDGE RECTIFIER

KBJ

Features

- Glass passivated chip junction KBJ
- Reliable low cost construction utilizing molded plastic technique
- Ideal for printed circuit board
- Low forward voltage drop
- Low reverse leakage current
- High surge current capability
- "-A" is an AEC-Q101 qualified device
- This is a Pb − Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: Molded plastic, KBJ
- Epoxy: UL 94V-O rate flame retardant
- Terminals: Leads solderable per MIL-STD-202, method 208 guaranteed
- Mounting position: Any
- Weight: 0.16ounce, 4.6gram

Maximum Ratings: @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	KBJ410G-A	Units
Marking code		**KBJ410G**	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_{DC}	1000	V
RMS Reverse Voltage	V_{RMS}	700	V
Average forward rectified output current @T_C= 115°C	I_O	4.0	A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	120	A

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Electrical Characteristics: @T_A=25°C unless otherwise specified

Type Number	Symbol	KBJ410G-A	Units
Forward Voltage (per element) @I_F =2A @I_F =4A	V_F	1.0 1.1	V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 125°C	I_{RM}	5.0 500	μA
Typical Junction Capacitance(per leg) (Note 1)	C_J	40	pF

* Pulse width < 300 μs, duty cycle < 2%

Thermal-Mechanical Specifications: @T_A=25°C unless otherwise specified

Type Number	Symbol	KBJ410G-A	Units
Typical Thermal Resistance(Note 2)	$R_{\theta JC}$	5.5	°C/W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	°C

Note: 1. Measured at 1 MHZ and applied reverse voltage of 4.0 VDC.
2. Thermal Resistance from Junction to Case with Device Mounted on 75mm x 75mm x 1.6mm Cu Plate Heatsink.

Ratings and Characteristics Curves

FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

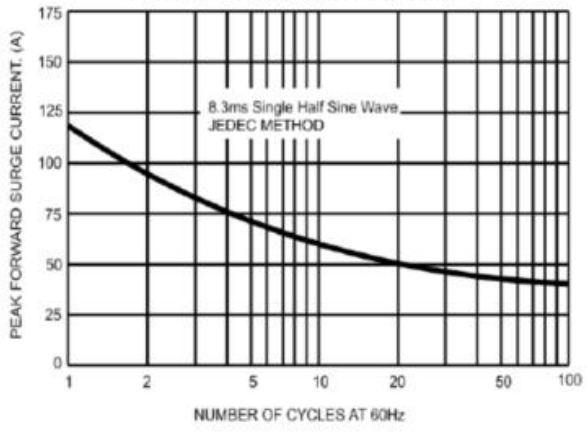

FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE PER BRIDGE ELEMENT

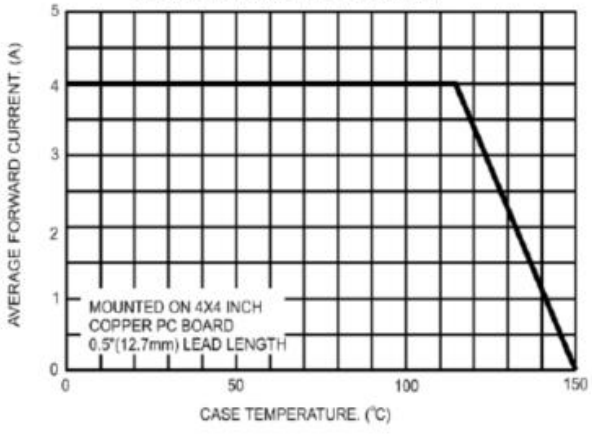

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FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

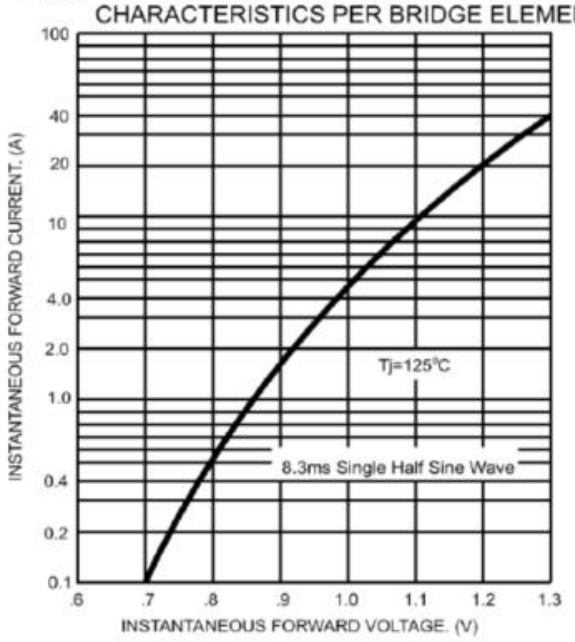
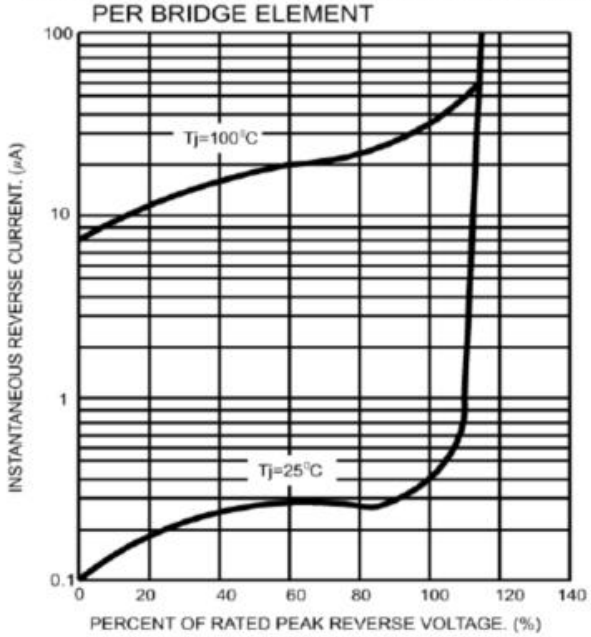


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT

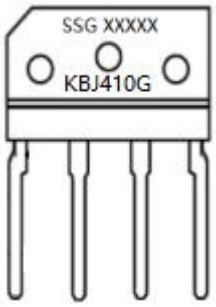


Ordering Information

Device	Package	Plating	Shipping
KBJ410G-A	KBJ (Pb-Free)	Pure Sn	250pcs / box

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

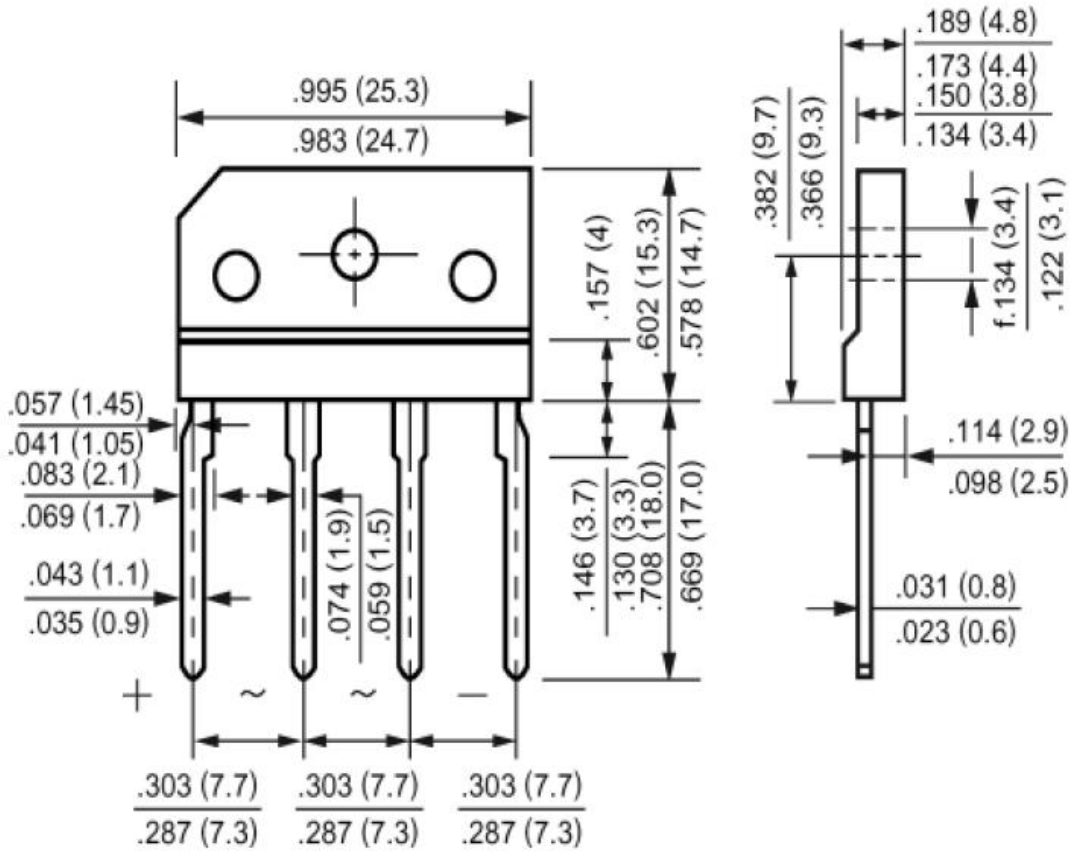


Where XXXXX is YYWWL

SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number
KBJ410G	= Marking code

Cautions: Molding resin
Epoxy resin UL:94V-0

Mechanical Dimensions KBJ (Inches/Millimeters)



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